

CMOS 8-Bit Addressable Latch

High-Voltage Types (20-Volt Rating)

■ CD4724B 8-bit addressable latch is a serial-input, parallel-output storage register that can perform a variety of functions.

Data are inputted to a particular bit in the latch when that bit is addressed (by-means of inputs A0, A1, A2) and when WRITE DISABLE is at a low level. When WRITE DISABLE is high, data entry is inhibited; however, all 8 outputs can be continuously read independent of WRITE DISABLE and address inputs.

A master RESET input is available, which resets all bits to a logic "O" level when RESET and WRITE DISABLE are at a high level. When RESET is at a high level, and WRITE DISABLE is at a low level, the latch acts as a 1-of-8 demultiplexer; the bit that is addressed has an active output which follows the data input, while all unaddressed bits are held to a logic "O" level.

The CD4724B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Feature

- Selial data input = Active parallel output
- Storage register capability Master clear
- Can function as demultiplexer
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
 Meximum input current of 1 μA at 18 V (full package-temperature range), 100 nA at 18 V and 25°C.
- Noise margin (full package-temperature range) = 1 V at VDD = 5 V, 2 V at VDD = 10 V, 2.5 V at VDD = 15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)	,
Voltages referenced to VSS Terminal)	ł.
NEW YOUTAGE RANGE, ALL INPUTS	1
DC INPUT CURRENT, ANY ONE INPUT	
DC INPUT CURHENT, ANT ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	,
For TA = -559C to + 100°C	ł.
For TA = +100°C to ±125°C Derate Linearity at 12mW/°C to 200mW	ł
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW	1
OPERATING-TEMPERATURE RANGE (TA)	5
OPERATING-TEMPERATURE HANGE (TA)	
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C	·
I SAN TEMPERATINE (DI IRING SOLDERING):	
At distance 1/18 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max	2

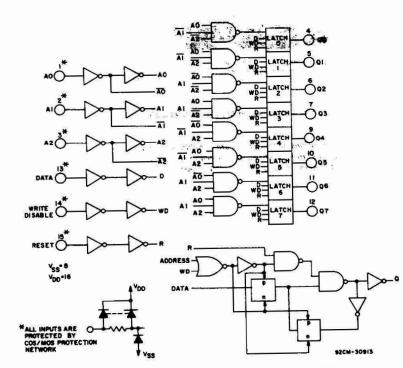
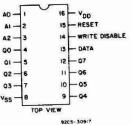
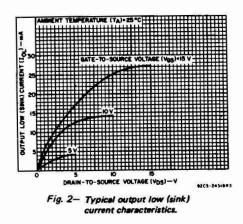


Fig. 1- Logic diagram of CD4724B and detail of 1 of 8 latches.

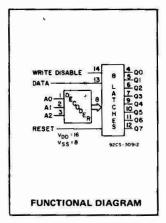


TERMINAL ASSIGNMENT



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CD4724B Types



Applications:

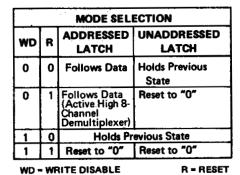
A/D converters

Multi-line decoders

CD4724B Types

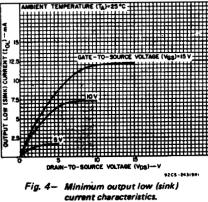
RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ} C$ (Unless other	rwise specified)
For maximum reliability, nominal operating conditions should be selected so	o that operation
is always within the following ranges.	

CHARACTERISTIC	SEE	V _{DD}	LIM	ITS	UNITS
	FIG. 15*	(V)	MIN.	MAX.	01113
Supply Voltage Range: (At T _A = Full Package Temperature Range)			3	18	v
Pulse Width, tw		5	200	~	
Data	(4)	10	100	-	
		15	80		
		5	400	-	ns
Address	(8)	10	200	1	115
		15	125	-	
		5	150	-	
Reset	(5)	10	75	· · -	
		15	50	-	
Setup Time, ts		5	100	-	
Data to WRITE DISABLE	6	10	50	-	
		15	35	-	ns
Hold Time, t _H		5	150	_	
Data to WRITE DISABLE	()	10	75	_	ns
	_	15	50	-	



AQ 30% 70 % A I A2 70% -

Fig. 3- Definition of WRITE DISABLE ON time.



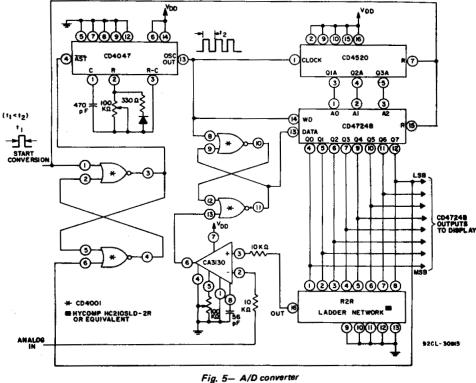
DRAM-TO-SOURCE VOLTAGE (VDS)

Fig.6 -- Typical output high (source) current characteristics.

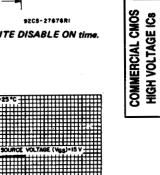
-10 -10

* Circled numbers refer to times indicated on master timing diagram.

Note: In addition to the above characteristics, a WRITE DISABLE ON time (the time that WRITE DISABLE is at a high level) must be observed during an address change for the total time that the external address lines A0, A1, and A2 are settling to a stable level, to prevent a wrong cell from being addressed +







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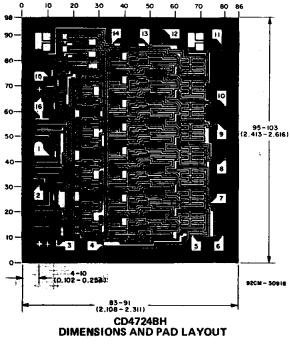
9205-2432083

92C5-27676RI

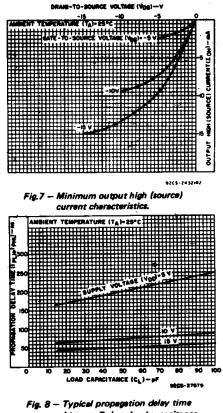
3

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	NTION	15	LIMITS AT INDICATED TEMPERATURES (°C)					UNITS		
ISTIC	Vo	VIN	VDD						+25		
	(V)	(V)	$\overline{(v)}$	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device	-	0,5	5	5	5	150	150	-	0.04	5	
Current,	-	0,10	10	10	10	300	300	-	0.04	10	μA
IDD Max.	_	0,15	15	20	20	600	600	-	0.04	20	μΑ
-	_	0,20	20	100	100	3000	3000		0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		1
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	. –	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
(Source)	2,5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	. –	
POH IMITE	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	· -	
Output Voltage:	-	0,5	5		0	.05		-	0	0.05	
Low-Level, Voi Max.		0,10	10		0	.05		_	0	0.05	1
	_	0,15	15		0	.05		-	0	0.05	
Output Voltage:	-	0,5	5		4	.95		4.95	5	-	
High-Level,	-	0,10	10		9	.95		9.95	10	-	
VOH Min.	-	0,15	15		14	1.95		14.95	15	-	
Input Low	0.5, 4.5	-	5		1	1.5		-	—	1.5	
Voltage,	1, 9	-	10			3		—		3	ļ
VIL Max.	1.5,13.5	-	15			4			-	4	
Input High	0.5, 4.5	-	5		3.5						· ·
Voltage,	1, 9	-	10		7			7	_		
VIH Min.	1.5,13.5	-	15		11					-	
Input Current IIN Max.	-	0,18	18	±0.1	±0.1	±1	±1	_ 	±10-5	±0.1	μA



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .



(deta to Qn) vs. load capacitance.

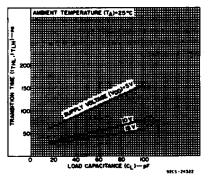


Fig. 9 — Typical transition time vs. load capacitance.

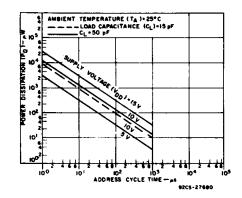
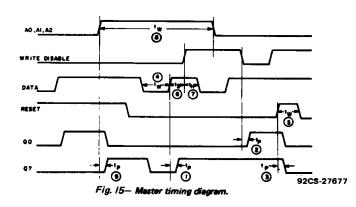


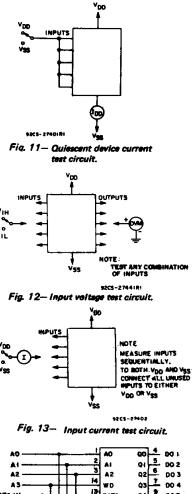
Fig.10 – Typical dynamic power dissipation vs. address cycle time.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ C$, $C_L = 50 \, pF$, Input t_r , $t_f = 20 \, ns$, $R_L = 200 \, K\Omega$

CHARACTERISTIC	CONDI SEE	TIONS VDD		NITS (AGE TYPES	UNITS	
	Fig. 15*	(V)	TYP.	MAX.		
Propagation Delay: tpLH,		5	200	400		
^t PHL	\bigcirc	10	75	150		
Data to Output,		15	50	100		
WRITE DISABLE		5	200	400		F
to Output, _{tPLH} ,	2	10	80	160	пs	
^t PHL		15	60	120		
		5	175	350		
Reset to Output,	3	10	80	160		V H 95
tphl		15	65	130		vîl
Address to Output,		5	225	450		
^t PLH	()	10	100	200		
^t PHL		15	75	150		
Transition Time, tTHL		5	100	200		F
(Any Output) #TLH		10	60	100	ns	
		15	40	80		
Minimum Pulse		5	100	200		۷ ₀₀ محم
Width, t _W	(4)	10	50	100	ns	v _{ss}
Data		15	40	80	4	
		5	200	400		
Address	8	10	100	200	ns	
		15	65	125		
		5	75	150		*
Reset	5	10	40	75	ns	A
		15	25	50		A
Minimum Setup		5	50	100		DATA I
Time, t _S	6	10	25	50	ns	
Data to WRITE DISABLE		15	20	35		
Minimum Hold		5	75	150		
Time, t _H	\bigcirc	10	40	75	ns	
Data to WRITE DISABLE		15	25	50		
Input Capacitance, CIN	Any Int	out	5	7.5	pF	

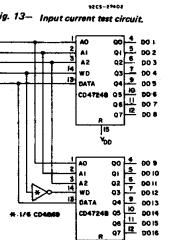
*Circled numbers refer to times indicated on master timing diagram.

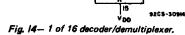


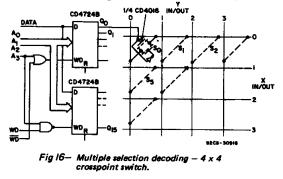


3

COMMERCIAL CMOS HIGH VOLTAGE IC8









PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD4724BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4724BE	Samples
CD4724BF3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4724BF3A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4724B, CD4724B-MIL :

Catalog : CD4724B

• Military : CD4724B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



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5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD4724BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4724BE	N	PDIP	16	25	506	13.97	11230	4.32

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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